

NEC

DATA SHEET

SILICON POWER TRANSISTOR 2SA1742

PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SA1742 is a power transistor developed for high-speed switching and features a high h_{FE} at low $V_{CE(sat)}$. This transistor is ideal for use as a driver in DC/DC converters and actuators.

In addition, a small resin-molded insulation type package contributes to high-density mounting and reduction of mounting cost.

FEATURES

- High h_{FE} and low $V_{CE(sat)}$:
 $h_{FE} \geq 100$ MIN. @ $V_{CE} = -2.0$ V, $I_C = -1.5$ A
 $V_{CE(sat)} \geq -0.3$ V MAX. @ $I_C = -4.0$ V, $I_B = -0.2$ A
- Full-mold package that does not require an insulating board or bushing

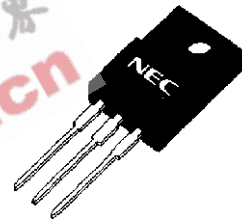
ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Ratings	Unit
Collector to base voltage	V_{CBO}		-100	V
Collector to emitter voltage	V_{CEO}		-60	V
Emitter to base voltage	V_{EBO}		-7.0	V
Collector current (DC)	$I_{C(DC)}$		-7.0	A
Collector current (pulse)	$I_{C(pulse)}$	$PW \leq 300 \mu s$, duty cycle $\leq 10\%$	-14	A
Base current (DC)	$I_{B(DC)}$		-3.5	A
Total power dissipation	P_T	$T_C = 25^\circ\text{C}$	30	W
		$T_A = 25^\circ\text{C}$	2.0	W
Junction temperature	T_J		150	$^\circ\text{C}$
Storage temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

ORDERING INFORMATION

Part No.	Package
2SA1742	Isolated TO-220

(Isolated TO-220)



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ELECTRICAL CHARACTERISTICS (T_A = 25°C)

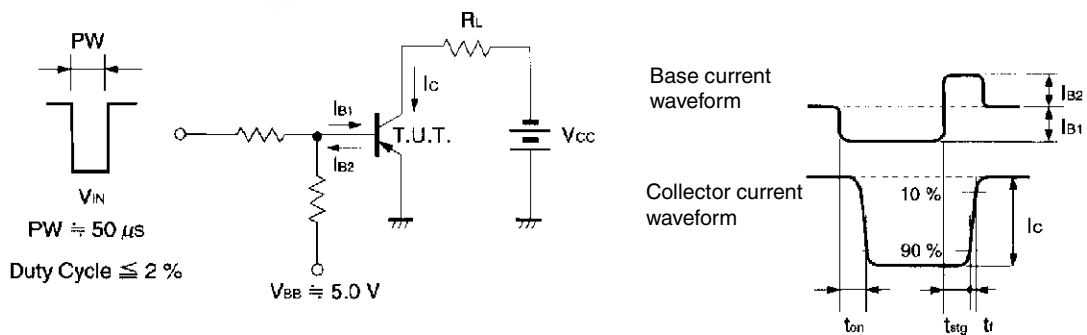
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	V _{CE0(SUS)}	I _C = -4.0 V, I _B = -0.4 A, L = 1 mH	-60			V
	V _{CEx(SUS)}	I _C = -4.0 A, I _{B1} = -I _{B2} = -0.4 A, V _{BE(OFF)} = 1.5 V, L = 180 μH, clamped	-60			V
Collector cutoff current	I _{CBO}	V _{CB} = -60 V, I _E = 0 A			-10	μA
	I _{CER}	V _{CE} = -60 V, R _{BE} = 50 Ω, T _A = 125°C			-1.0	mA
	I _{CEx1}	V _{CE} = -60 V, V _{BE(OFF)} = 1.5 V			-10	μA
	I _{CEx2}	V _{CE} = -60 V, V _{BE(OFF)} = 1.5 V, T _A = 125°C			-1.0	mA
Emitter cutoff current	I _{EBO}	V _{EB} = -5.0 V, I _C = 0 A			-10	μA
DC current gain	h _{FE1}	V _{CE} = -2.0 V, I _C = -0.7 A ^{Note}	100			
	h _{FE2}	V _{CE} = -2.0 V, I _C = -1.5 A ^{Note}	100		400	
	h _{FE3}	V _{CE} = -2.0 V, I _C = -4.0 A ^{Note}	60			
Collector saturation voltage	V _{CE(sat)1}	I _C = -4.0 A, I _B = -0.2 A ^{Note}			-0.3	V
	V _{CE(sat)2}	I _C = -6.0 A, I _B = -0.3 A ^{Note}			-0.5	V
Base saturation voltage	V _{BE(sat)1}	I _C = -4.0 A, I _B = -0.2 A ^{Note}			-1.2	V
	V _{BE(sat)2}	I _C = -6.0 A, I _B = -0.3 A ^{Note}			-1.5	V
Collector capacitance	C _{ob}	V _{CB} = -10 V, I _E = 0 A, f = 1.0 MHz		180		pF
Gain bandwidth product	f _T	V _{CB} = -10 V, I _C = -1.0 A		40		MHz
Turn-on time	t _{on}	I _C = -4.0 A, R _L = 12.5 Ω, I _{B1} = -I _{B2} = -0.2 A, V _{CC} ≅ -50 V Refer to the test circuit.			0.3	μs
Storage time	t _{stg}				1.5	μs
Fall time	t _f				0.3	μs

Note Pulse test PW ≤ 350 μs, duty cycle ≤ 2%

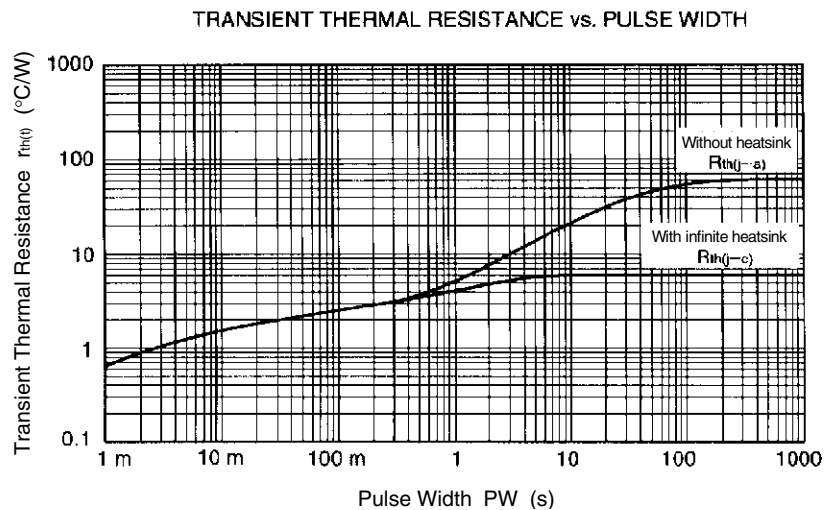
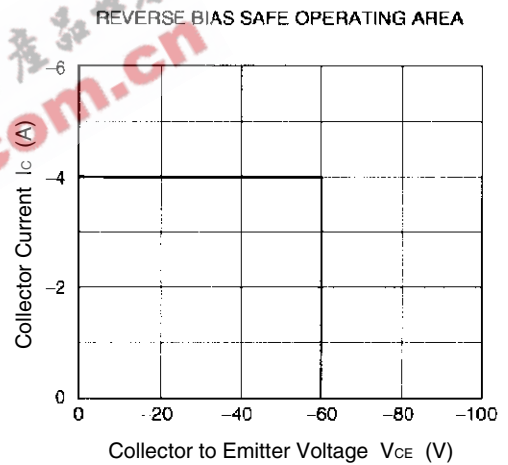
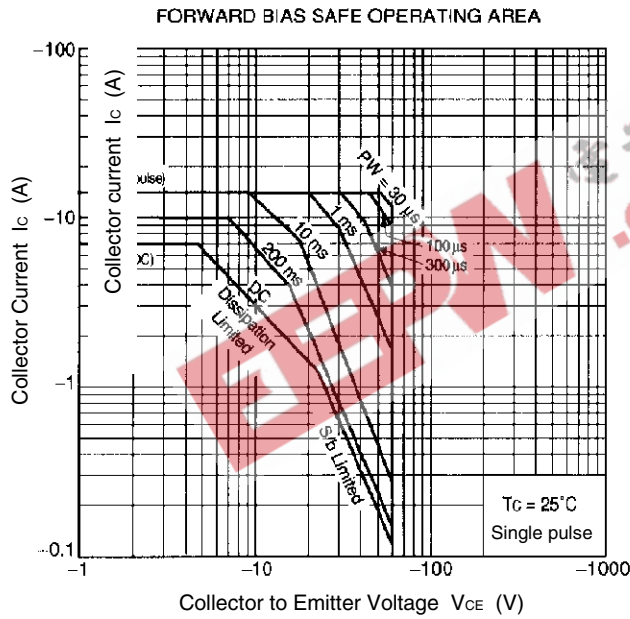
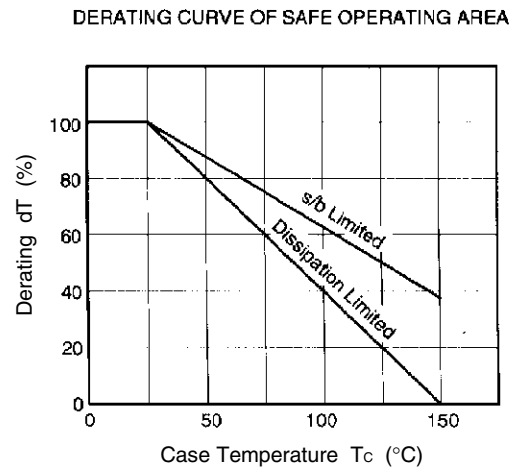
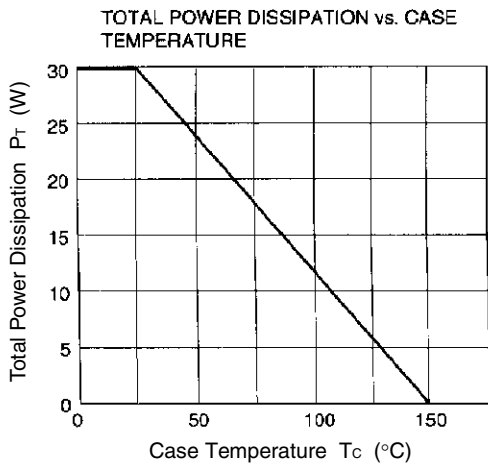
h_{FE} CLASSIFICATION

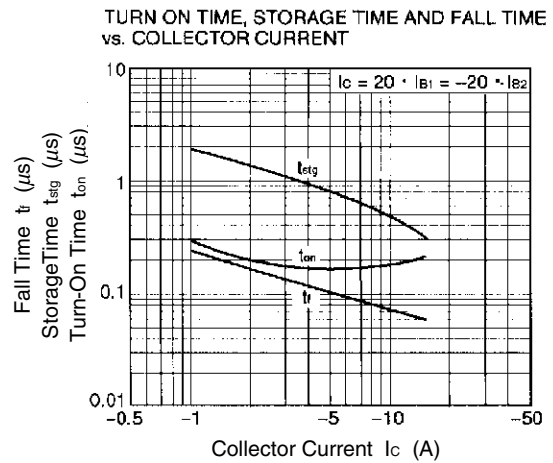
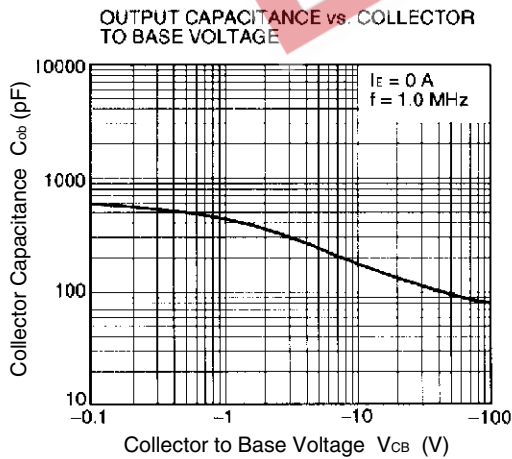
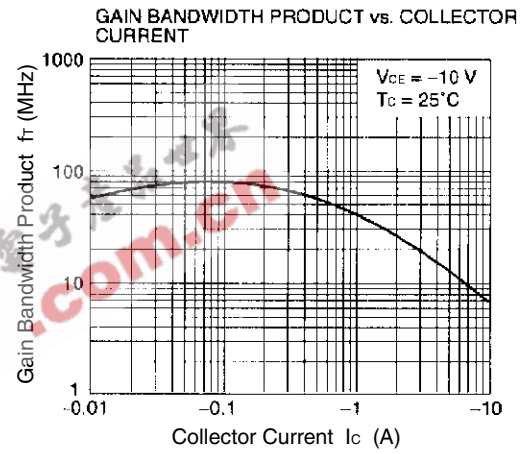
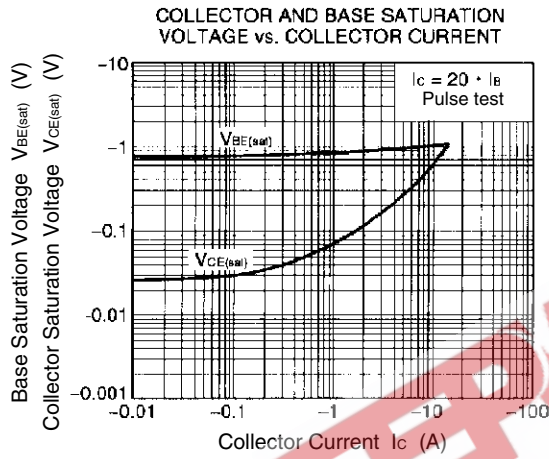
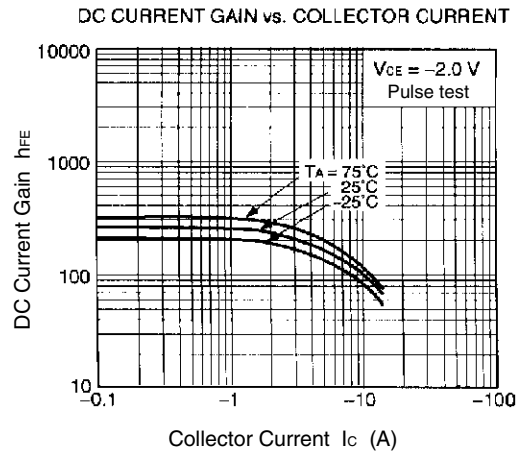
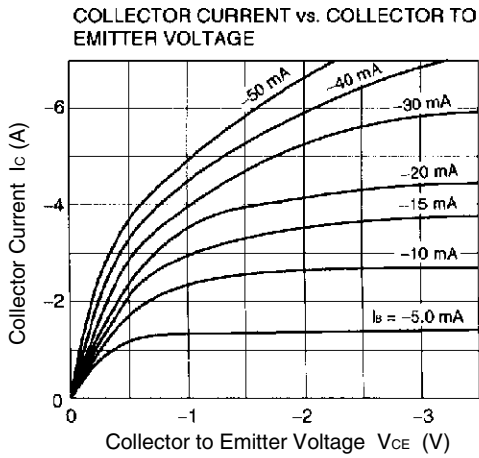
Marking	M	L	K
h _{FE2}	100 to 200	150 to 300	200 to 400

SWITCHING TIME (t_{on}, t_{stg}, t_f) TEST CIRCUIT



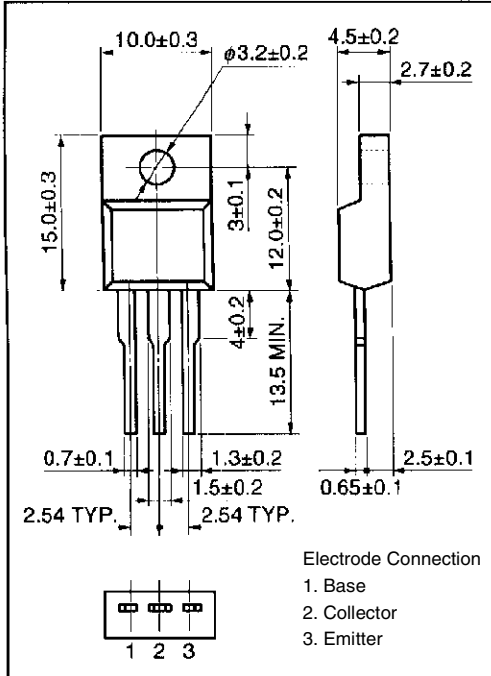
TYPICAL CHARACTERISTICS (T_A = 25°C)





PACKAGE DRAWING (UNIT: mm)

Isolated TO-220



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